

Vishay General Semiconductor

Dual High-Voltage Trench MOS Barrier Schottky Rectifier

Ultra Low $V_F = 0.24 \text{ V}$ at $I_F = 5 \text{ A}$



PRIMARY CHARACTERISTICS				
I _{F(AV)}	2 x 30 A			
V_{RRM}	45 V			
I _{FSM}	400 A			
V _F at I _F = 30 A (T _A = 125 °C)	0.41 V			
T _J max.	150 °C			
Package	TO-3PW			
Diode variations	Dual common cathode			

FEATURES

- Trench MOS Schottky technology
- · Low forward voltage drop, low power losses

• High efficiency operation

RoHS COMPLIANT

- Solder dip 275 °C max. 10 s, per JESD 22-B106 FREE
- Material categorization: For definitions of compliance please see <u>www.vishay.com/doc?99912</u>

TYPICAL APPLICATIONS

For use in high frequency converters, switching power supplies, freewheeling diodes, OR-ing diode, DC/DC converters and reverse battery protection.

MECHANICAL DATA

Case: TO-3PW

Molding compound meets UL 94 V-0 flammability rating Base P/N-M3 - halogen-free, RoHS-compliant, and

commercial grade

Terminals: Matte tin plated leads, solderable per

J-STD-002 and JESD 22-B102

M3 suffix meets JESD 201 class 1A whisker test

Polarity: As marked

Mounting Torque: 10 in-lbs maximum

MAXIMUM RATINGS (T _A = 25 °C unless otherwise noted)					
PARAMETER		SYMBOL	VT60L45PW	UNIT	
Maximum repetitive peak reverse voltage		V _{RRM}	45	V	
Maximum average forward rectified current (fig. 1)	per device		60	۸	
	per diode	I _{F(AV)}	30	A	
Peak forward surge current 8.3 ms single half sine-wave superimposed on rated load per diode		I _{FSM}	400	А	
Operating junction and storage temperature range		T _J , T _{STG}	-40 to +150	°C	



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ELECTRICAL CHARACTERISTICS (T _A = 25 °C unless otherwise noted)							
PARAMETER	TEST CONDITIONS		SYMBOL	TYP.	MAX.	UNIT	
Instantaneous forward voltage per diode	I _F = 5 A	T _A = 25 °C	V _F ⁽¹⁾	0.37	-	V	
	I _F = 15 A			0.43	-		
	I _F = 30 A			0.49	0.57		
	I _F = 5 A	T _A = 125 °C		0.24	-		
	I _F = 15 A			0.32	-		
	I _F = 30 A			0.41	0.50		
Reverse current per diode	V _R = 45 V	T _A = 25 °C	I _R ⁽²⁾	-	7	mA	
	v _R = 45 v	T _A = 125 °C		67	180	mA	

Notes

(1) Pulse test: 300 μs pulse width, 1 % duty cycle

(2) Pulse test: Pulse width ≤ 5 ms

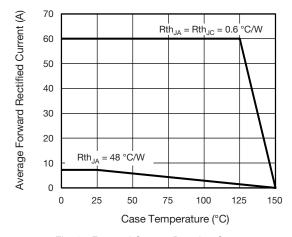
THERMAL CHARACTERISTICS (T _A = 25 °C unless otherwise noted)					
PARAMETER		SYMBOL	VT60L45PW	UNIT	
Typical thermal resistance	per diode	- R _{θJC}	0.9		
	per device		0.6	°C/W	
	per device	R _{θJA} ⁽¹⁾⁽²⁾	48		

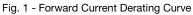
Notes

- (1) The heat generated must be less than the thermal conductivity from junction-to-ambient: $dP_D/dT_J < 1/R_{\theta JA}$
- (2) Free air, without heatsink

ORDERING INFORMATION (Example)						
PACKAGE	CKAGE PREFERRED P/N UNIT WEIGHT (g)		PACKAGE CODE	BASE QUANTITY	DELIVERY MODE	
TO-3PW	VT60L45PW-M3/4W	4.5	4W	30/tube	Tube	

RATINGS AND CHARACTERISTICS CURVES (T_A = 25 °C unless otherwise noted)





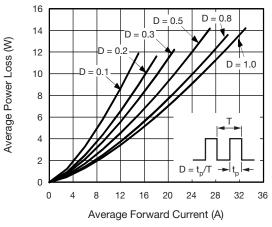


Fig. 2 - Forward Power Loss Characteristics Per Diode



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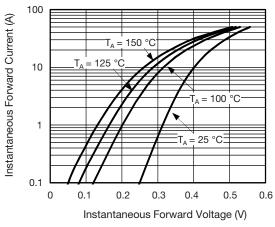


Fig. 3 - Typical Instantaneous Forward Characteristics Per Diode

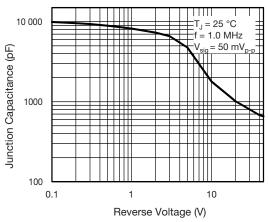


Fig. 5 - Typical Junction Capacitance Per Diode

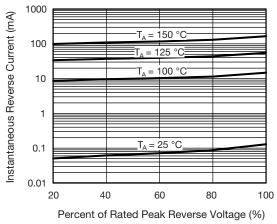


Fig. 4 - Typical Reverse Characteristics Per Diode

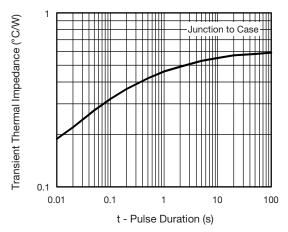
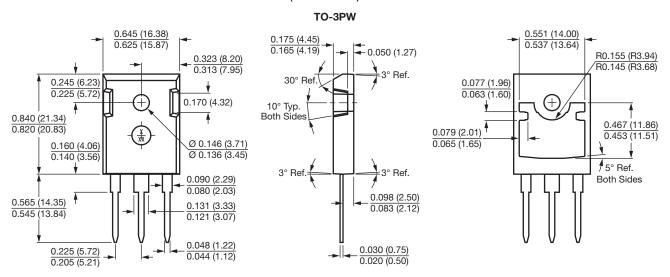


Fig. 6 - Typical Transient Thermal Impedance Per Diode

PACKAGE OUTLINE DIMENSIONS in inches (millimeters)





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